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A-71760/AJT/TJH
463031-139

CERTIFICATE OF MAILING (37 CFR 1.8(a))

I hereby certify that this correspondence (along with any referred to as being attached or enclosed) is being deposited with the United States Postal Service with sufficient postage as First Class Mail in an envelope addressed to: Commissioner for Patents, P.O. Box 1450, Alexandria, VA 22313-1450 on May 14, 2004.

Signature: _____

Laura Lee Mosier

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re application of:

LAZAREV et al.

Serial No. 10/656,578

Filed: September 4, 2003

For: *Organic Photosensitive Optoelectronic Device*

Art Unit: 1772

Examiner: To be assigned

Date: May 14, 2004

**INFORMATION DISCLOSURE STATEMENT SUBMITTED
PRIOR TO THE FIRST OFFICIAL ACTION**

Commissioner for Patents
P.O. Box 1450
Alexandria, VA 22313-1450

Dear Sir:

In satisfaction of the duty of disclosure under 37 C.F.R. § 1.56, and in accordance with the provisions of 37 C.F.R. §§ 1.97 and 1.98, Applicants wish to draw the attention of the U.S. Patent and Trademark Office to the references cited on the accompanying form PTO/SB/08A-08B. In accordance with 1273 Off. Gaz. Pat. Off. 1, 8/5/2003, no copies of U.S. patents and U.S. published applications are enclosed. Further, in accordance with the provisions of 37 C.F.R. § 1.98(b)(5)(c), Applicant submits that reference no. C17 is substantively cumulative, in which a copy of the publication is not submitted, and that this publication is considered cumulative. Copies of all other references are enclosed.

None of the foregoing references is believed to disclose the invention as claimed. Nothing herein shall constitute an admission concerning the contents of any of the cited references, nor shall the inclusion of a reference herein be considered an admission that the

reference constitutes prior art against the invention claimed in the above-identified application. Submission of the present document shall not be construed as an admission that a search has been made or that better art does not exist.

As far as is known to the undersigned, this Information Disclosure Statement is being filed within three months of the filing date of a national application, within three months of the date of entry of the national state in an international application, or before the mailing date of a first Office Action on the merits as set forth in 37 C.F.R. § 1.97(b), and therefore no fee is required.

While no fee is believed to be due, if this belief is in error the Commissioner is authorized to charge any additional fees, including extension fees or other relief which may be required, or credit any overpayment to Deposit Account No. 50-2319 (Our Order No. 463031-139 [A-71760/AJT/TJH]).

Please direct any calls in connection with this application to the undersigned at (650) 494-8700.

Respectfully submitted,

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(463031-139)

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INFORMATION DISCLOSURE STATEMENT BY APPLICANT <i>(use as many sheets as necessary)</i>				Complete if Known	
				Application Number	10/656,578
				Filing Date	September 4, 2003
				First Named Inventor	Pavel I. LAZAREV
				Group Art Unit	1772
Examiner Name	Not yet assigned				
Sheet	2	of	2	Attorney Docket Number	A-71760/AJT/TJH (463031-139)
NON PATENT LITERATURE DOCUMENTS					
Examiner Initials*	Cite No. ¹	Include name of the author (in CAPITAL LETTERS), title of the article (when appropriate), title of the item (book, magazine, journal, serial, symposium, catalog, etc.), date, page(s), volume-issue number(s), publisher, city and/or country where published.			T ²
	C1	ASHIDA, M., et al., "Thermal Transformation of Vacuum-Condensed Thin Films of Copper-Phthalocyanine", <i>Journal of Crystal Growth</i> , 1971, 8:45-56.			
	C2	ASHIDA, M., et al., "Unit Cell Metastable-form Constants of Various Phthalocyanines", <i>Bulletin of the Chemical Society of Japan</i> , 1966, 39(12): 2616-2624.			
	C3	ASHIDA, M., "The Orientation Overgrowth of Metal-phthalocyanines on the Surface of Single Crystals. I. Vacuum-condensed Films on Muscovite", <i>Bulletin of the Chemical Society of Japan</i> , 1966, 39(12): pp. 2625-2631.			
	C4	ASHIDA, M., "The Orientation Overgrowth of Metal-phthalocyanines on the Surface of Single Crystals. II. Vacuum-condensed Films of Copper-phthalocyanine on Alkali Halides", 1966, 39(12): 2632-2638.			
	C5	BOBROV, Y., "Spectral properties of Thin Crystal Film Polarizers", <i>Molecular Materials</i> , 2001, 14(3):191-203.			
	C6	DITTMER, "Photovoltaic Properties of MEH-PPV/PPEI Blend Devices", J.J., et al., <i>Synthetic Metals</i> , 1999, 102:879-880.			
	C7	FRYER, J.R., "Molecular Images of Thin-Film Polymorphs and Phase Transformations in Metal-Free Phthalocyanine", <i>Acta Cryst.</i> , 1979, A35, pp. 327-332.			
	C8	HIRAMOTO, M., et al., "Photocurrent multiplication in organic pigment films", <i>Appl. Phys. Lett.</i> , 1994, 64(2): 187-189.			
	C9	LAZAREV, P., et al., "X-ray Diffraction by Large Area Organic Crystalline Nano-Films", <i>Molecular Materials</i> , 2001, 14(4): 303-311.			
	C10	McPHERSON, A., "Facilitation of the Growth of Protein Crystals by Heterogeneous/Epitaxial Nucleation", <i>Journal of Crystal Growth</i> , 1988, 85:206-214.			
	C11	MURATA, Y. et al., "Molecular image of copper phthalocyanine", <i>Journal of Microscopy</i> , December 1976, Vol. 108, Pt., 3, pp. 261-275.			
	C12	NAZEERUDDIN, M.K., et al., "Conversion of Light to Electricity by <i>cis</i> -X ₂ Bis(2,2'-bipyridyl-4,4'-dicarboxylate)ruthenium(II) Charge-Transfer Sensitizers (X=Cl ⁻ , Br ⁻ , I ⁻ , CN ⁻ , and SCN ⁻) on Nanocrystalline TiO ₂ Electrodes", <i>J. Am. Chem. Soc.</i> , 1993, 115 (14): 6382-6390.			
	C13	PETRITSCH, K., Ph.D. Thesis, "Organic Solar Cell Architectures", Cambridge and Graz, July 2000, Chapters 3 and 4, Single Layer Devices, p. 31 and p. 67.			
	C14	SAIJO, H. et al., "Epitaxial Growth of a New Polymorph of Cu-Phthalocyanine on Graphite", <i>Journal of Crystal Growth</i> , 1977, 40: 118-124.			
	C15	SAITO, Y., "Epitaxial Growth Mechanism of Chlorinated Copper Phthalocyanine on KCl Surfaces", <i>Appl. Surf. Sci.</i> , 1985, 22/23, pp. 574-581.			
	C16	SAITO, Yoshio et al., "Molecular Energetics of the Epitaxial Growth of Chlorinated Copper Phthalocyanine on KCl surfaces", <i>Journal of Crystal Growth</i> , 1984, 67:91-96.			
	C17	SZE, S.M., <i>Physics of Semiconductor Devices</i> , Wiley-Interscience, New York, 1981. (Not included)			
	C18	UYEDA, N. et al., "Molecular image resolution in electron microscopy", <i>J. App. Phys.</i> , Vol. 43, No. 12, December 1972, pp. 5181-5189.			
Examiner Signature				Date Considered	